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SINGLE DIGIT LED DISPLAY (0.39Inch)

Lead-Free Parts

LSD375/61-XX-PF

DATA SHEET

DOC. NO : QW0905-LSD375/61-XX-PF

REV. : A

DATE : 26 - Mar.-2007

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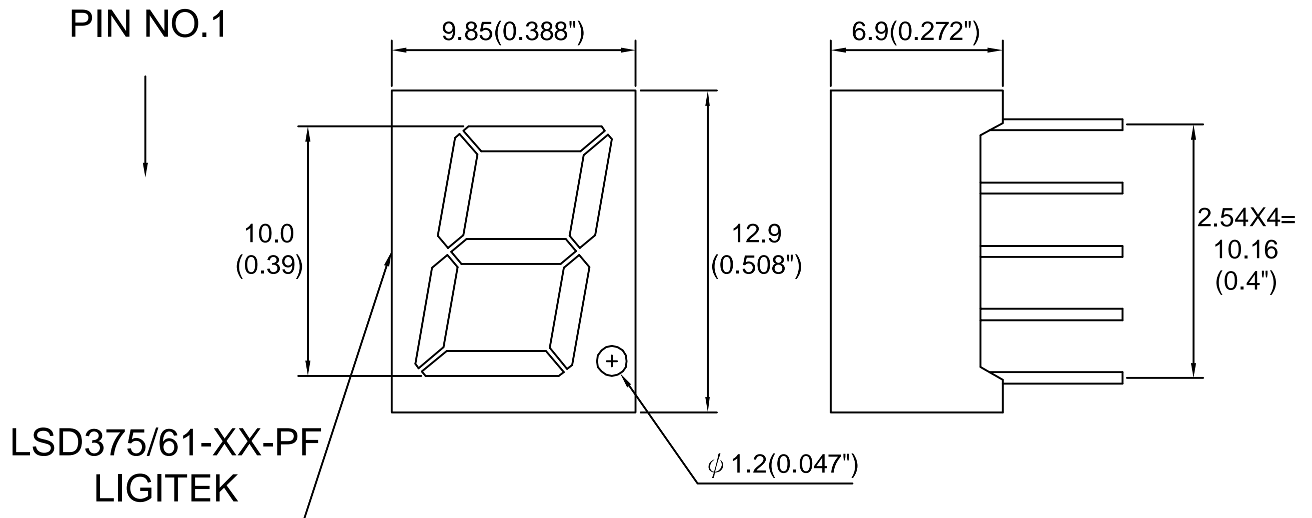
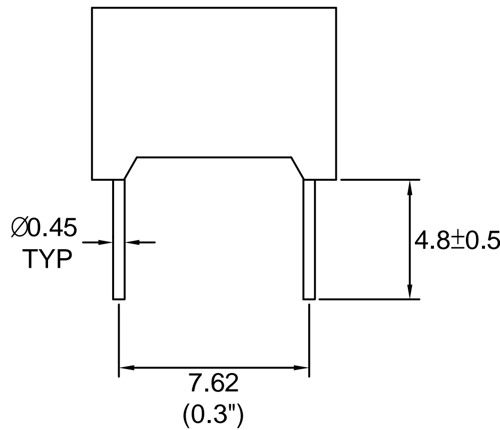
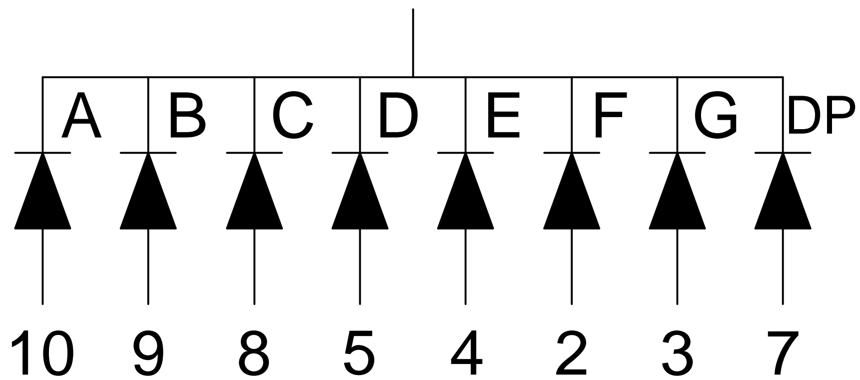
Package Dimensions

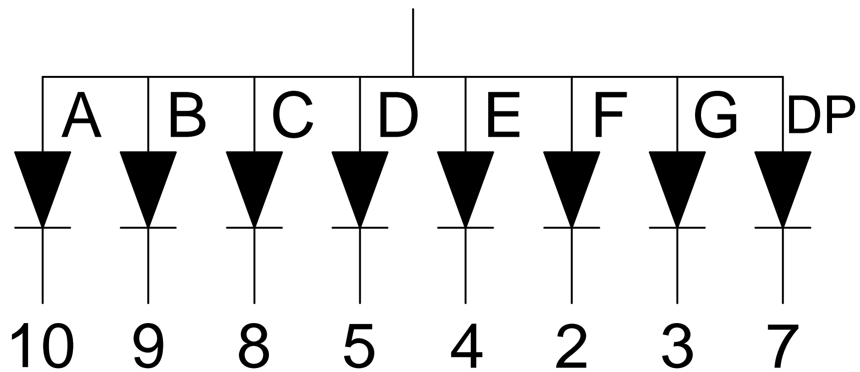




Note : 1.All dimension are in millimeters and (Inch) tolerance is ±0.25(0.01") unless otherwise noted.
2.Specifications are subject to change without notice.

Internal Circuit Diagram





Electrical Connection

PIN NO.	LSD3751-XX-PF	PIN NO.	LSD3761-XX-PF
1	Common Cathode	1	Common Anode
2	Anode F	2	Cathode F
3	Anode G	3	Cathode G
4	Anode E	4	Cathode E
5	Anode D	5	Cathode D
6	Common Cathode	6	Common Anode
7	Anode DP	7	Cathode DP
8	Anode C	8	Cathode C
9	Anode B	9	Cathode B
10	Anode A	10	Cathode A

Absolute Maximum Ratings at Ta=25 ℃

Parameter	Symbol	Ratings	UNIT
		H	
Forward Current Per Chip	I_F	15	mA
Peak Forward Current Per Chip (Duty 1/10,0.1ms Pulse Width)	I_{FP}	60	mA
Power Dissipation Per Chip	PD	40	mW
Reverse Current Per Any Chip	Ir	10	μA
Operating Temperature	T_{opr}	-25 ~ +85	℃
Storage Temperature	Tstg	-25 ~ +85	℃
Solder Temperature 1/16 Inch Below Seating Plane For 3 Seconds At 260 ℃			

Part Selection And Application Information(Ratings at 25℃)

PART NO	CHIP		common cathode or anode	λP (nm)	△λ (nm)	Electrical					IV-M
						Vf(v)			Iv(mcd)		
	Material	Emitted				Min.	Typ.	Max.	Min.	Typ.	
LSD3751-XX-PF	GaP	Red	Common Cathode	697	90	1.7	2.1	2.6	0.5	0.8	2:1
LSD3761-XX-PF	GaP	Red	Common Anode	697	90	1.7	2.1	2.6	0.5	0.8	2:1

Note : 1.The forward voltage data did not including ±0.1V testing tolerance.
2. The luminous intensity data did not including ±15% testing tolerance.

Test Condition For Each Parameter

Parameter	Symbol	Unit	Test Condition
Forward Voltage Per Chip	Vf	volt	If=20mA
Luminous Intensity Per Chip	Iv	mcd	If=10mA
Peak Wavelength	λP	nm	If=20mA
Spectral Line Half-Width	△λ	nm	If=20mA
Reverse Current Any Chip	Ir	μA	Vr=5V
Luminous Intensity Matching Ratio	IV-M		

Typical Electro-Optical Characteristics Curve

H CHIP

Fig.1 Forward current vs. Forward Voltage

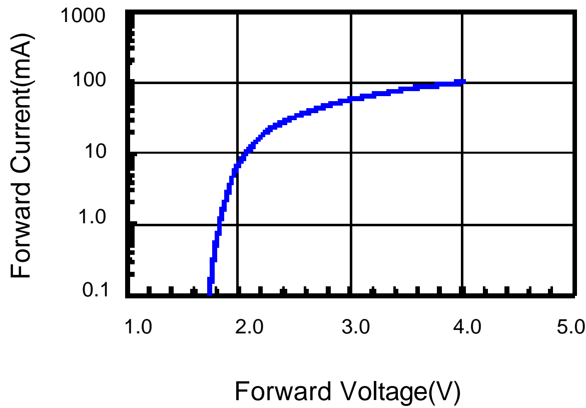


Fig.2 Relative Intensity vs. Forward Current

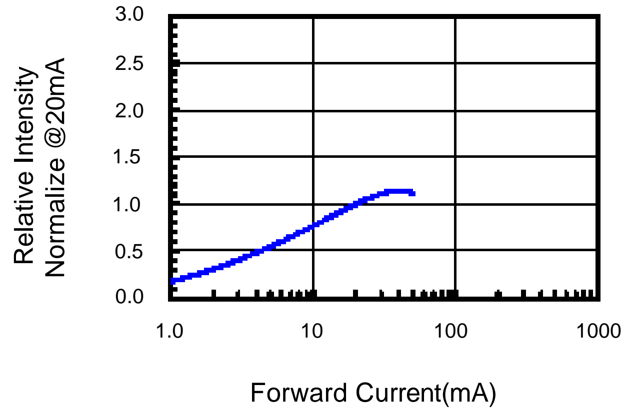


Fig.3 Forward Voltage vs. Temperature

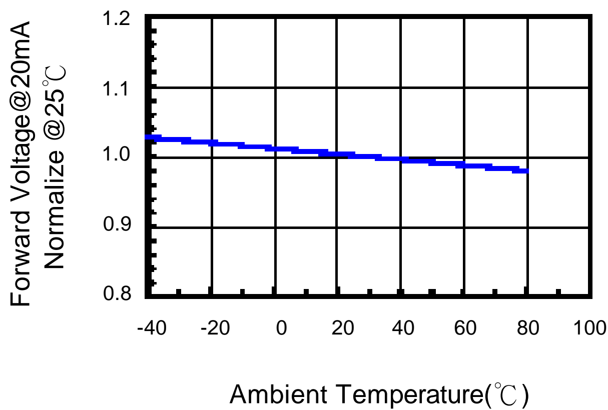


Fig.4 Relative Intensity vs. Temperature

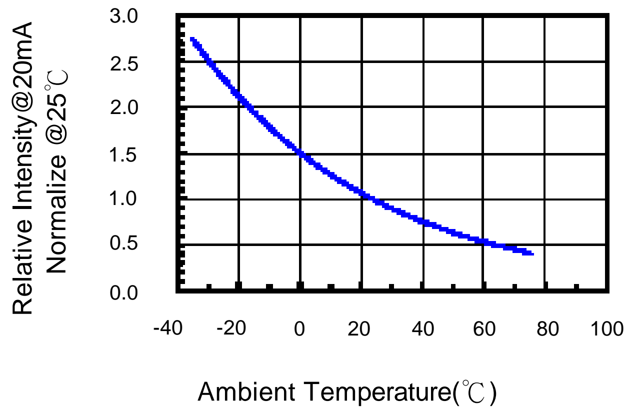
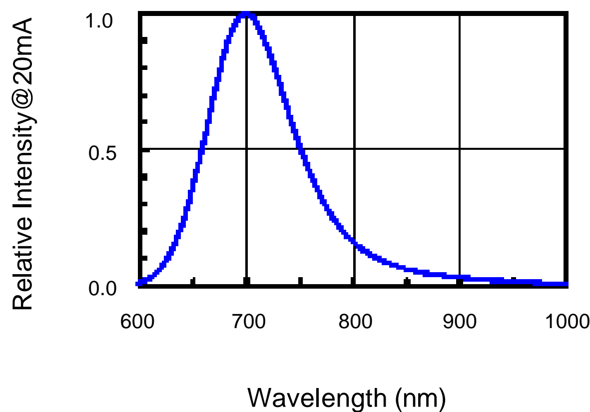


Fig.5 Relative Intensity vs. Wavelength



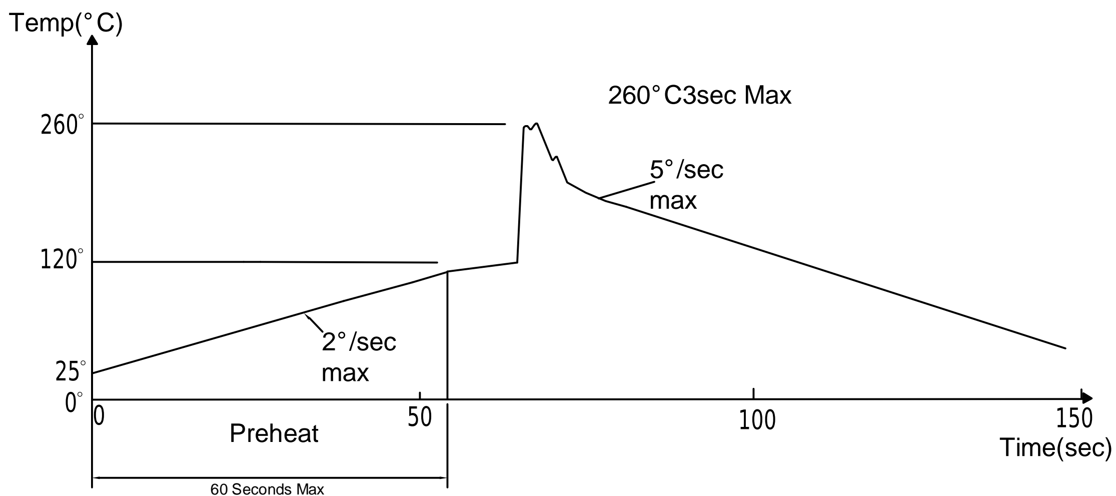
Soldering Condition(Pb-Free)

1.Iron:

Soldering Iron:30W Max
Temperature 350°C Max
Soldering Time:3 Seconds Max(One time only)
Distance:Solder Temperature 1/16 Inch Below Seating Plane For 3 Seconds At 260°C

2.Wave Soldering Profile

Dip Soldering
Preheat: 120°C Max
Preheat time: 60seconds Max
Ramp-up
2°C/sec(max)
Ramp-Down:-5°C/sec(max)
Solder Bath:260°C Max
Dipping Time:3 seconds Max
Distance:Solder Temperature 1/16 Inch Below Seating Plane For 3 Seconds At 260°C



Note: 1.Wave solder should not be made more than one time.
2.You can just only select one of the soldering conditions as above.

Reliability Test:

Test Item	Test Condition	Description	Reference Standard
Operating Life Test	1.Under Room Temperature 2.If=10mA 3.t=1000 hrs (-24hrs, +72hrs)	This test is conducted for the purpose of detemining the resistance of a part in electrical and themal stressed.	MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1
High Temperature Storage Test	1.Ta=105℃±5℃ 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.	MIL-STD-883:1008 JIS C 7021: B-10
Low Temperature Storage Test	1.Ta=-40℃±5℃ 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.	JIS C 7021: B-12
High Temperature High Humidity Test	1.Ta=65℃±5℃ 2.RH=90%~95% 3.t=240hrs±2hrs	The purpose of this test is the resistance of the device under tropical for hours.	MIL-STD-202:103B JIS C 7021: B-11
Thermal Shock Test	1.Ta=105℃±5℃&-40℃±5℃ (10min) (10min) 2.total 10 cycles	The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.	MIL-STD-202: 107D MIL-STD-750: 1051 MIL-STD-883: 1011
Solder Resistance Test	1.T.Sol=260℃±5℃ 2.Dwell time= 10±1sec.	This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire.	MIL-STD-202: 210A MIL-STD-750: 2031 JIS C 7021: A-1
Solderability Test	1.T.Sol=230℃±5℃ 2.Dwell time=5±1sec	This test intended to see soldering well performed or not.	MIL-STD-202: 208D MIL-STD-750: 2026 MIL-STD-883: 2003 JIS C 7021: A-2